

Final Exam, ECE 137A

Wednesday March 20, 2019, Noon - 3 p.m.

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Closed Book Exam:

Class Crib-Sheet and 4 pages (4 surfaces) of student notes permitted

Do not open this exam until instructed to do so. Use any and all reasonable approximations (5% accuracy), *after stating & justifying them.*

Show your work:

Full credit will not be given for correct answers if supporting work is missing.

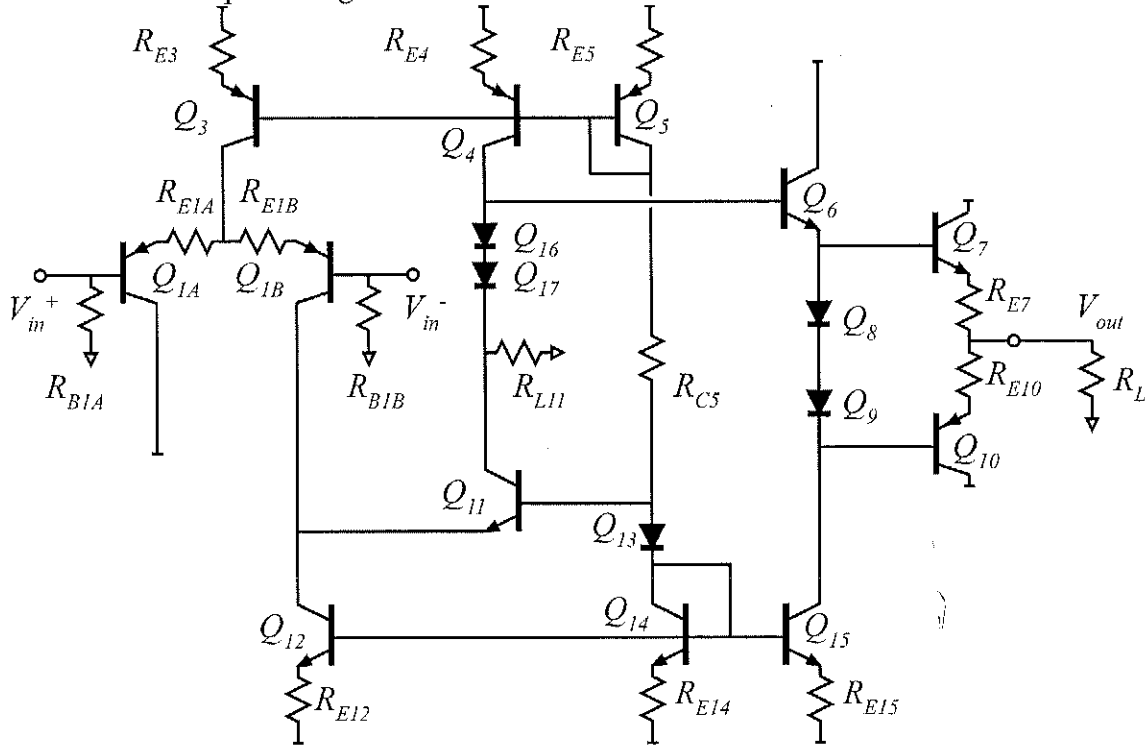
Good luck

Time function	LaPlace Transform
$\delta(t)$ impulse	1
$U(t)$ unit step-function	$1/s$
$e^{-\alpha t}U(t)$	$\frac{1}{s+\alpha} = \frac{1/\alpha}{1+s/\alpha}$
$e^{-\alpha t} \cos(\omega_d t)U(t)$	$\frac{s+\alpha}{(s+\alpha)^2 + \omega_d^2}$
$e^{-\alpha t} \sin(\omega_d t)U(t)$	$\frac{\omega_d}{(s+\alpha)^2 + \omega_d^2}$

Part	Points Received	Points Possible	Part	Points Received	Points Possible
1a		6	2c		15
1b		5	2d		10
1c		4	3a		7
1d		10	3b		8
1e		10	3c		7
2a		10	3d		8
2b		10			
total		100			

Problem 1, 35 points

This is an NOT an Op-Amp: Analyze under the assumption that the differential and common mode input voltages are at zero volts



All the transistors have the same (matched) I_S , have $\beta = 100$, and $V_A = \infty$ Volts.

$V_{CE(sat)} = 0.5V$.

V_{be} is approximately 0.7 V,

but use $V_{be} = (kT/q) \ln(I_E / I_S)$ when necessary or appropriate.

The supplies are +3 Volts and -3 Volts.

All transistors (and diodes) have the same I_S

Q1A,1B,5,11 are biased at 5mA collector current.

Q6 is biased at 20mA collector current.

Q7 and Q10 are biased at 5mA collector current.

The DC voltage drops across RE5 and RE14 are both 300mV.

RB1A=RB1B=2kOhm. RE1A=RE1B=44.8Ohm. RL11=1.1kOhm.

RL=1kOhm.

Part a, 6 points

DC bias---to simplify, assume $\beta = \infty$ for the DC analysis only.

Find the value of the following resistors:

Re5=_____ Re14=_____ Re4=_____

Re15=_____ Re12=_____ Re3=_____

Re7=_____ Re10=_____

$$1 \quad \left[R_{E3} = \frac{300mV}{10\mu A} = 30\Omega = R_{E12} \right]$$

$$1 \quad \left[R_{E4} = \frac{300mV}{5\mu A} = 60\Omega = R_{E5} = R_{E14} \right]$$

$$1 \quad \left[R_{E15} = \frac{300mV}{20\mu A} = 15\Omega \right]$$

$$3 \quad \left[R_{E7} = R_{E10} = \frac{V_T}{5\mu A} \ln\left(\frac{20\mu A}{5\mu A}\right) \approx 7.2\Omega \right]$$

Part c, 4 points

find the following

device	Q1AB	11	12	4	6	15	7	10
gm, mS								

Q 1A, 1B, 11, 14

$$I_C = 5 \text{ mA} \rightarrow g_m = \frac{5 \text{ mA}}{26 \text{ mV}} = \frac{1}{5.2 \Omega} = 192 \text{ mS}$$

Q 12, 3

$$I_C = 10 \text{ mA} \quad g_m = \frac{10 \text{ mA}}{26 \text{ mV}} = \frac{1}{2.6 \Omega} = 385 \text{ mS}$$

Q 6, 15

$$I_C = 20 \text{ mA} \quad g_m = \frac{20 \text{ mA}}{26 \text{ mV}} = \frac{1}{1.3 \Omega} = 769 \text{ mS}$$

Q 7, 10

$$I_C = 5 \text{ mA} \quad g_m = \frac{5 \text{ mA}}{26 \text{ mV}} = \frac{1}{5.2 \Omega} = 192 \text{ mS}$$

Part d, 10 points.

Find the following, *using the actual value of β , i.e. $\beta=100$*

	Voltage Gain	Input impedance
Q1AB	0.0583	1.43k Ω
Q11	188.6	5.83k Ω
Q6	1	10k Ω
Q7	0.989 \approx 1	100k Ω
Overall differential Vout/Vin	11	1.43k Ω

Note: with some insight, you can find the combined gain of Q1AB/11 in a single step. If you would like to do so, omit the separate answers for Q1AB and Q11 in the table above, and instead fill in the table below,

	Voltage Gain	Input impedance
Q1AB/ Q11 combination.	11	1.43k Ω

Note - $R_{CC} = 0\Omega$ - simplifies calculations

We can treat Q7, 10 as both on, or on one at a time.

TA's: Wide range of assumptions ok for this part.

⊙ Treat Q7 as on / 10 as off.

$$Q7: \text{EF: } A_v = \frac{1k\Omega}{1k\Omega + 5.2k\Omega + 7.2k\Omega} = 0.988 \approx 1$$

$$R_{i7} = \beta (1k\Omega + 5.2k\Omega + 7.2k\Omega) \approx \beta (1k\Omega) = 100k\Omega$$

Q6: 5P

$$R_{eq} = R_{in7} = 100k\Omega$$

$$A_v = \frac{100k\Omega}{100k\Omega + 7.2k\Omega + 5.2k\Omega} \approx 1$$

$$R_{i6} \approx \beta(100k\Omega) = 10M\Omega$$

Q11 - common base.

$$R_{base} = (1/g_{m13} + 1/g_{m14} + R_{E14}) \parallel (R_{C5} + 1/g_{m5} + R_{E5})$$

$$= (5.2k\Omega + 5.2k\Omega + 60\Omega) \parallel (600\Omega + 5.2k\Omega + 60\Omega)$$

$$= 70.4k\Omega \parallel 725\Omega = 64\Omega$$

(-1 pt for using $R_E = 0\Omega$)

$$R_{in11} = 1/g_m + R_{base}/\beta = 5.2k\Omega + \frac{64\Omega}{100} = 5.83\Omega$$

$$R_{L11} = R_{L11} \parallel R_{in6} = 1.1k\Omega \parallel 10M\Omega \approx 1.1k\Omega$$

$$A_{v11} = \frac{1.1k\Omega}{5.83\Omega} = 188.6$$

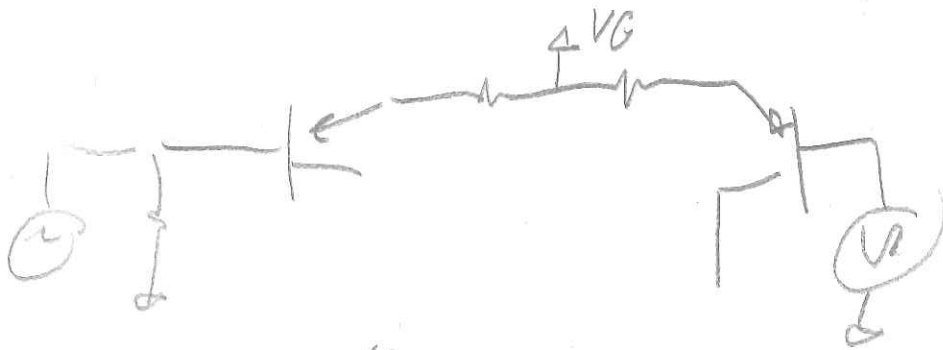
Q1A 11B

$$R_{eq} = R_{in11} = 5.83\Omega$$

$$A_v = \frac{R_{eq}}{2(1/g_m + R_{E1})} = \frac{5.83\Omega}{2(5.2k\Omega + 44.9\Omega)} = \frac{5.83\Omega}{201} = 0.029$$

or wait on next pg.

Input impedance depends on input circuit.



$$\begin{aligned}
 Z_i &= 2k\Omega \parallel \beta (r_{be} + R_{e1}) \\
 &= 2k\Omega \parallel 100(50\Omega) = 2k\Omega \parallel 5k\Omega \\
 &= 1.43k\Omega
 \end{aligned}$$

or the $\beta R_{e1} \parallel$ combin.

$$A_v = \frac{R_{c1} \parallel R_L}{\beta (r_{be} + R_{e1})} = \frac{1.1k\Omega}{100\Omega} = 11$$

or A_{v1}

Part e, 10 points

Maximum peak-peak output voltage (*show all your work*)

For this, you must use the full circuit diagram, not the half circuit diagram.

	magnitude and sign of maximum output signal swing due to <i>cutoff</i>	magnitude and sign of maximum output signal swing due to <i>saturation</i>
Transistor Q7	Not Relevant	2.47V
Transistor Q10	N. R.	-2.47V
Transistor Q6	-2000V	+1.78V
Transistor Q15	NR - no signal	-1.5V
Transistor Q4	NR - no signal	0.8V
Transistor Q11	+5.5V	-2.2V
Transistor Q1A	+5.5V	omit
Transistor Q1B	-5.5V	omit

Be warned: In some cases a limit is not relevant at all. Mark those answers "not relevant". But, give a 1-sentence statement below as to why it is not relevant. Q7/10 form a push pull stage, so be careful about your answer there. .

1/2 [Q7 cutoff - not relevant push-pull

1/2 [Q7 saturation: $V_{out} = (3V - V_{CEsat}) \frac{1k\Omega}{1k\Omega + 7.2\Omega + 5.2\Omega} = (3V - 1/2V) 0.988 = 2.47V$

[Q10 same as Q7 - polarities reversed.

[Q6 saturation: $V_{out} = (V_{CC} - V_{CEsat6} - V_{CEsat7}) (0.988) = (3V - 1/2V - 0.7V) 0.988 = (1.8V) 0.988 = 1.78V$

[Q6 cutoff: $\Delta V_{out} = -I_{C6} R_{eq7} = 2000V / 100k\Omega \cdot 0.99 = -2000V \cdot 0.99 = -2000V$

[Q15 saturation: $V_{out} = (-2.7V + V_{CEsat6}) 0.99 = -2.2V (0.99) = -2.2V$

Q4 saturated:

$$V_{out} = (+2.7V - V_{ce,sat} - V_{be6} - V_{be7}) \cdot 0.99 \\ \approx 2.7V - 1.2V - 1.4V = 0.8V.$$

Q11 saturated:

$$V_{out} = (-2.0V + V_{ce,sat} + V_{be16} + V_{be17} - V_{be1} - V_{be7}) \cdot 0.99 \\ \approx -2.0V + 0.5V = -1.5V.$$

Q1A cutoff:

If $I_{C1A} \rightarrow 0mA$ for $I_{C1B} = 10mA$
and $I_{C11} = 0mA$

$$\Rightarrow \Delta V_{C11} = 5mA \cdot 1.1k\Omega = +5.5V$$

$$\Delta V_{out} = 5.5V (0.99) \approx 5.5V.$$

Q1B cutoff - same as above, but with signs reversed.

$$\Delta V_{out} = -5.5V.$$

Q11 cutoff:

$$\Delta I_C = 5mA \rightarrow \Delta V_{C11} = 5mA \cdot 1.1k\Omega \\ = +5.5V$$

$$\Delta V_{out} = 5.5V (0.99) \approx 5.5V.$$

Ignore $(1 + \lambda V_{DS})$ term

Part a, 10 points

DC bias.

Analyze the bias under the assumption that DC output voltage is zero volts, that the positive input V_{i+} is zero volts, and that we must determine the DC value of the negative input voltage (V_{i-}) necessary to obtain this.

(Hint, this should give $V_{i-} = 0V$)

Find the following:

Gate widths of M12 and M13 = _____

Gate width of M7 = _____

Gate width of M8 = _____

Gate width of M9 = _____

$$I_D = 0.55 \mu A / V^2 (V_{GS} - V_{th})^2 (1 + \lambda V_{DS})$$

$$M_{12,13}: W_g = \frac{50 \mu A}{0.55 \mu A / V^2 (0.1 V)^2} = 9 \mu m$$

$$M_7: W_g = \frac{35 \mu A}{0.55 \mu A / V^2 (0.2 V)^2} = 1.6 \mu m$$

$$M_{8/9}: W_g = \frac{25 \mu A}{0.55 \mu A / V^2 (0.05 V)^2} = 18 \mu m$$

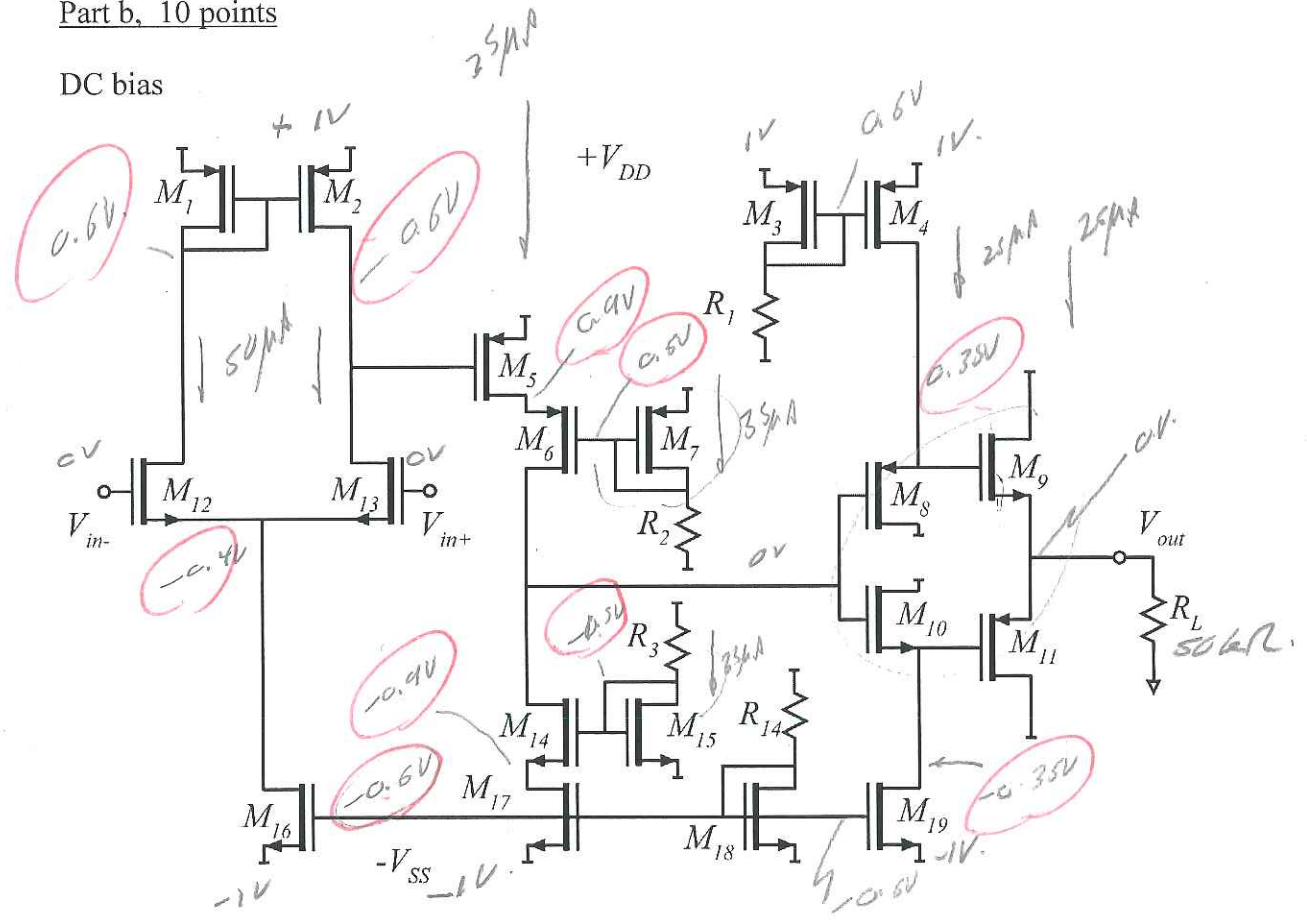
333 equal

$K_n = 0.55 \text{ mA/V}^2 \cdot \frac{W}{L}$ $1/\lambda = 20 \text{ V}$

$V_{HL} = 0.3 \text{ V}$

Part b, 10 points

DC bias



On the circuit diagram above, label the DC voltages at ALL nodes, the drain currents of ALL transistors, and the gate widths of ALL transistors

1 each

Part c, 15 points.

You will now compute the op-amp differential gain. Find the following

	Voltage Gain	Input impedance
Transistor combination M1,2,13, 13	~ 200	$\infty \Omega$
M5,6 combination	80,000	"
Q9 or Q12: M8 or M10	~ 1	"
Q8 or Q15: M10 or M11	~ 1	"
Overall differential Vout/Vin	16 Million	$\infty \Omega$

Notes:

1) You can analyse M5 and M6 as separate stages, or as a combined stage using Norton/Thevenin methods. Don't ask for hints as to how to do this.

2) For M8/9 and for M10/11, you can assume that M8 and M9 are on for the positive signal swing and M10 and M11 are on for the negative signal swing. More accurately, you can assume, for the signal swing near zero volts, that all are on. If you take the latter approach (and do it correctly), you will receive a couple of extra credit points. One hint (don't ask for any other hints): use symmetry.

M8 & M11 take both * as on (signal near 0V)
each effectively draws $2R = 100k\Omega$.

$$R_{eq9} = R_{o59} \parallel 100k\Omega = \frac{1}{\lambda I_D} \parallel 100k\Omega = \frac{20V}{29\mu A} \parallel 100k\Omega$$

$$= 89k\Omega$$

(if we take M9 on, M10 off $\rightarrow R_{eq} \approx 47k\Omega - ok$)

$$A_{v9/11} = \frac{89k\Omega}{89k\Omega + 1k\Omega} \quad ; \quad g_m = \frac{2I_D}{V_{GS} - V_{th}} = \frac{2(25\mu A)}{50mV} = 1mS$$

$$= 0.989$$

$R_{i9} = \infty \Omega$

M6 or M10

$$\frac{1}{2} \left[r_{DS4} = r_{DS8} = \frac{1}{\lambda I_D} = \frac{20V}{25\mu A} = 800k\Omega \right]$$

$$\left[R_{Leg} = r_{DS4} \parallel r_{DS8} = 400k\Omega \right]$$

$$\frac{1}{2} \left[g_m = 2 I_D / (V_{GS} - V_{th}) = 2(25\mu A) / 50mV = 1mS \right]$$

$$1 \left[A_v = \frac{400k\Omega}{400k\Omega + 19k\Omega} = 0.9988 \approx 1 \right]$$

$$\underline{M5} \frac{1}{2} \left[r_{DS14} = r_{DS17} = 1 / \lambda I_D = 20V / 35\mu A = 571k\Omega \right]$$

$$\frac{1}{2} \left[g_{m14} = g_{m17} = g_{m5} = g_{m6} = 2(35\mu A) / (V_{GS} - V_{th}) \right]$$

$$\approx 70\mu A / 0.1V = 0.7mS$$

Notes that M7 is biased at $V_{DS} = V_{GS} \Rightarrow$ ok.
 $R_{out} = r_{DS} = 1 / \lambda I_D$

$$1 \left[R_{out14} = r_{DS} (1 + g_m r_{DS}) \approx g_m r_{DS}^2 \right]$$

$$1 \left[R_{Leg6} = R_{out14} = g_m r_{DS}^2 \right]$$

$$1 \left[R_{in6} = \frac{1}{g_m} \left(1 + \frac{R_{Leg6}}{r_{DS}} \right) = \frac{1}{g_m} \left[1 + \frac{g_m r_{DS}^2}{r_{DS}} \right] \approx r_{DS} \quad (!) \right]$$

$$1 \left[A_{v6} = R_{Leg6} / R_{in6} \approx g_m r_{DS} \right]$$

$$\frac{1}{2} \left[R_{Leg5} = r_{DS5} \parallel R_{in6} = r_{DS} \parallel r_{DS} = r_{DS} / 2 \right]$$

$$1 \left[A_{v5} = -g_m R_{Leg} = -g_m r_{DS} / 2 \right]$$

So:

$$1 \left[A_{v5} A_{v6} \approx (-g_m r_{DS} / 2) (g_m r_{DS}) = -(g_m r_{DS})^2 / 2 \right]$$

$$= -(0.7mS \cdot 571k\Omega)^2 / 2 = \underline{\underline{-80,000}}$$

$$\underline{M1, 2, 12, 13} \quad \frac{1}{2} \left[g_{m12,13} = \frac{2 I_D}{(V_{GS} - V_{th})} = \frac{2 (50 \mu A)}{0.1 V} = 1 mS \right]$$

$$\frac{1}{2} \left[R_{DS} = 1 / I_D = 20 V / 50 \mu A = 400 k\Omega \right]$$

$$\frac{1}{2} \left[R_{eq} = R_{DS2} \parallel R_{DS13} = R_{DS} / 2 \right]$$

$$\left[A_v = g_m R_{eq} = g_m R_{DS} / 2 \right]$$

$$= \underline{200}$$

M6 sat

$$V_{gs} = 0.9V, V_{t1} = 0.3V \rightarrow V_{ssat} = 0.1V$$

maximum drain voltage = $0.9V - 0.1V = 0.8V$

$$\Delta V_{out} = 0.8V, A_{v8} A_{v9} \approx 0.8V$$

M6 cutoff

Thevenin impedance @ M6 drain:

$$= R_{out6} \parallel R_{in14} = 9m\Omega_{gs}^2 / 2$$

$$\text{max. min } \Delta I = 35\mu A$$

$$\Delta V = -35\mu A (9m\Omega_{gs}^2 / 2) A_{v8} A_{v9}$$
$$= -4000V (!)$$

M14 cutoff: not relevant, no sig. d.

M14 sat

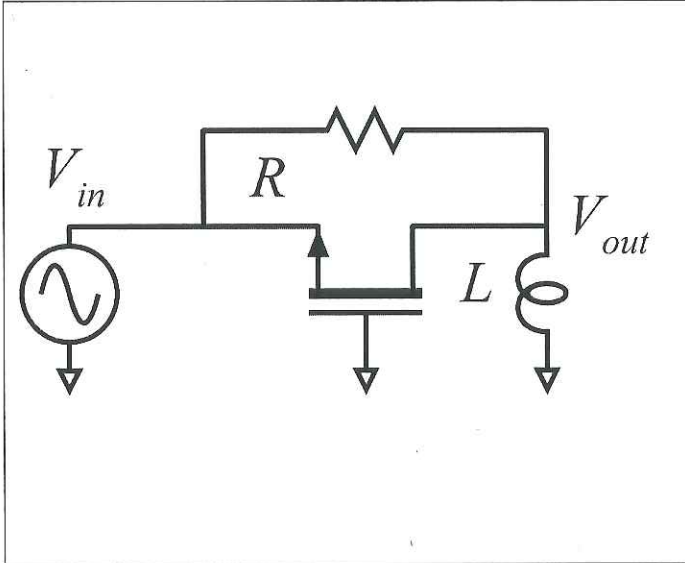
$$V_{gs, sat} = 0.1V$$

$$\Delta V_{out} = (-0.9V + 0.1V) A_{v8} A_{v9} = -0.8V$$

overall, can drive $\pm 0.55V$

as limited by M8, M19 saturation.

Problem 3, 30 points



You will be working on the circuit to the left

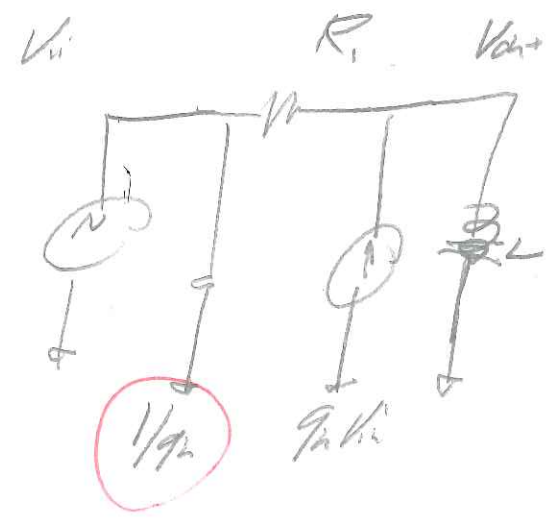
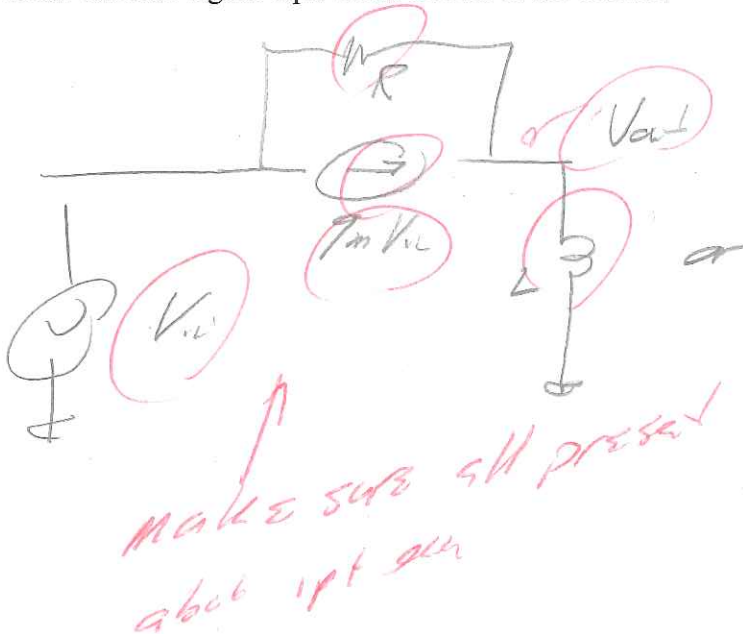
Ignore DC bias analysis. You don't need it.

The transistor has transconductance g_m .

Its output resistance R_{ds} is infinity...so you don't need to include this element in the circuit diagram !

Part a, 7 points

Draw a small-signal equivalent circuit of the circuit.



Part b, 8 points

$g_m = 10 \text{ mS}$, $L = 1 \text{ nH}$, $R = 1000 \text{ Ohms}$

Find, by nodal analysis, a small-signal expression for V_{out}/V_{in} . Be sure to give the answer with ****correct units**** and in ratio-of-polynomials form, i.e.

$$\frac{V_{out}(s)}{V_{gen}(s)} = K \cdot \frac{1 + b_1s + b_2s^2 + \dots}{1 + a_1s + a_2s^2 + \dots} \text{ or (as appropriate) } \frac{V_{out}(s)}{V_{gen}(s)} = K \cdot (s\tau)^n \cdot \frac{1 + b_1s + b_2s^2 + \dots}{1 + a_1s + a_2s^2 + \dots}$$

Note that an expression like

$$\frac{V_{out}(s)}{V_{gen}(s)} = \frac{1}{1 + (3 \cdot 10^{-6})s} \text{ is dimensionally wrong; } \frac{1}{1 + (3 \cdot 10^{-6} \text{ seconds})s} \text{ is dimensionally correct}$$

$V_{out}(s)/V_{in}(s) = \underline{\hspace{2cm}}$

2 $\left[\sum I = 0 \text{ @ } V_{out} \text{ (} G = 1/R \text{)}$

3 $\left[(V_{out} - V_{in})G + V_{out}/sL - g_m V_{in} = 0$

$$V_{out} (G + 1/sL) = V_{in} (g_m + G)$$

$$\frac{V_{out}}{V_{in}} = \frac{g_m + G}{G + 1/sL} = \frac{g_m + G}{G} \cdot \frac{1}{1 + R/sL}$$

$$= (1 + g_m R) \frac{s(L/R)}{1 + s(L/R)}$$

$$L/R = 1 \mu\text{s}$$

3 $\left[\frac{V_{out}}{V_{in}} = 11 \cdot \frac{s(1 \mu\text{s})}{1 + s(1 \mu\text{s})} \right]$

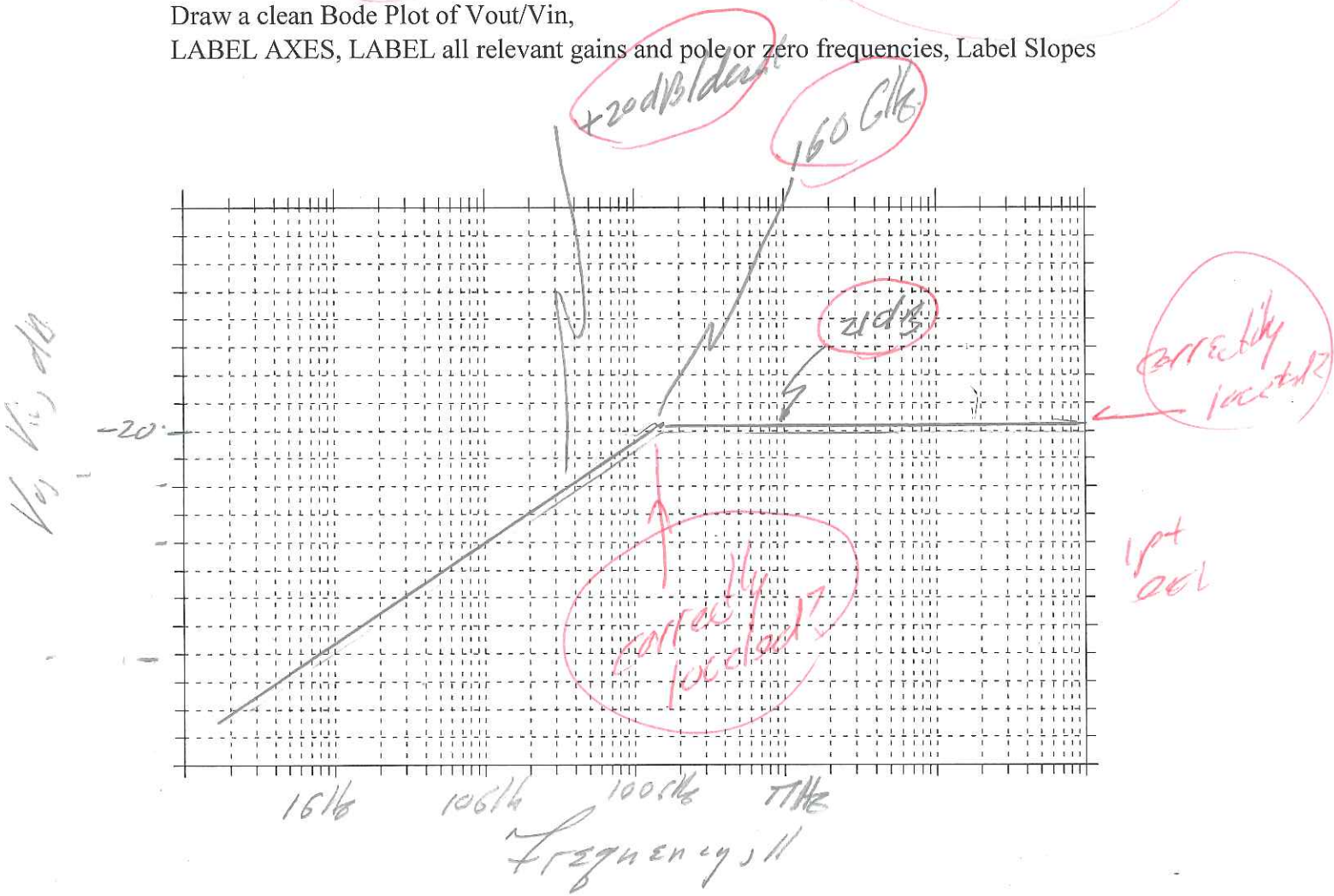
Part c, 7 points

Find any/all pole and zero frequencies of the transfer function, in Hz:

$f_{zoo} = 0 \text{ Hz}$, $f_{pole} = 1/2\pi \cdot 1\text{ps} = 159 \text{ GHz}$

Draw a clean Bode Plot of V_{out}/V_{in} ,

LABEL AXES, LABEL all relevant gains and pole or zero frequencies, Label Slopes



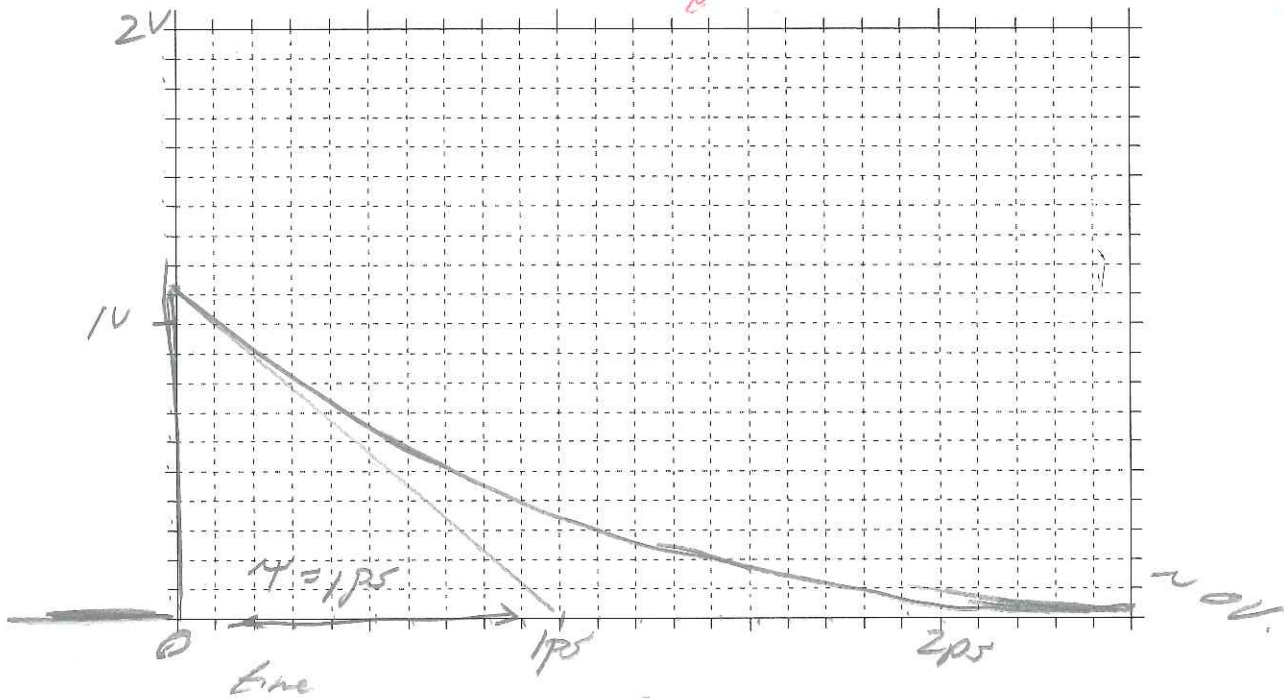
Part d, 8 points

$V_{in}(t)$ is a 0.1 V amplitude step-function.

Find $V_{out}(t) =$ _____

Plot it below. Label axes, show initial and final values, show time constants.

4 pts for correct & accurate graph



$$V_{out}(s) = \frac{1 \cdot \frac{1(sps)}{1 + 0.1(sps)}}{s} = 1.1V \cdot \frac{1ps}{1 + 1(sps)}$$

$$V_{out}(t) = 1.1V \cdot u(t) \cdot e^{-t/1ps}$$

4